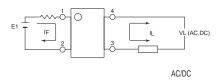
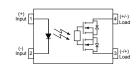


Parameter	Symbol	Rating	Units	
Load Voltage	VL	360	V	
Load Current	lι	0.8	Α	
On-Resistance	Ron	0.8	Ω	
I/O Breakdown Voltage	V/ıo	2500	Vrms	







- LED Anode
  LED Cathode
- 3.4. Drain(MOS FET)

(Unit: mm)



### **APSEMI PhotoRelays**

APSEMI Photorelays are the most reliable, technically advanced logic-to-power interface devices. Their basic function is to take a low current signal from a microprocessor to control the switching of both AC and DC loads, while providing an isolation barrier between logic and power. While this function is common to all relays, Photorelays provide distinct advantages over their mechanical counterparts including:

- Long life (No limit on mechanical and electrical
- lifetime)Bounce-free switching
- Higher speed and high frequency switching
- Higher sensitivity (less power consumption)
- Immunity to EMI or RFI

- No have voltaic arc, bounce, and noise More
- resistant to vibration and impact AC or DC load
- switching
- Small package size

#### **Function**

APSEMI PhotoRelays operate by taking a low level input current (<5mA) that energizes an input Infrared LED, which is optically-coupled to a Photo-diode array chip. This IC in turn generates a photo voltage that powers two MOSFETs typically connected in a source-to-source con¦ guration, allowing for both AC and DC output loads. Photorelay basically move photons to accomplish their switching function, they incur no mechanical wear and tear, providing consistent reliable switching.

# **Applications**

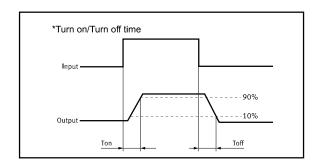
These advantages make APSEI Photorelays the ideal choice for:

- Telecom/Datacom switching
- Multiplexers
- Meter reading systems
- Data acquisition
- Medical equipment
- Battery monitoring
- I/O Sub-Systems

- Robotics
- Aerospace
- Home/Safety security systems
- Process Control
- Energy Management
- Reed Relay EMR Replacement
- Programmable Controllers

### **TPYES**

Catagoni		Output Rating		Doolsono	Part No.	Packing Overtity	
	Category	Load Voltage	Load Current	Package	Part No.	Packing Quantity	
	AC/DC	360V	0.8A	SOP-4	APY253GS	2000pcs /reel	





# Absolute Maximum Ratings (Ta = 25°C)

Item		Symbol	Value	Units	Note
	Continuous LED Current	lF	50	mA	
Input	Peak LED Current	<b>I</b> FP	1000	mA	f=100Hz, duty=1%
·	LED Reverse Voltage	VR	5	V	
	Input Power Dissipation	Pın	75	mW	
	Load Voltage	V∟	360	V(AC peak or DC)	
	Load Current	IL	0.8	Α	
Output	Peak Load Current	Peak	2.0	Α	100ms(1 pulse)
	Output Power Dissipation	Pout	400	mW	
Total Power	Dissipation	Р⊤	450	mW	
I/O Breakdown Voltage		V <sub>I/O</sub>	2500	Vrms	RH=60%, 1min
Operating Temperature		Торг	-40 to 85	°C	
Storage Temperature		T <sub>stg</sub>	-40 to 100	°C	
Pin Soldering Temperature		T <sub>sol</sub>	260	°C	10 sec max.

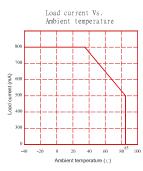
# Electrical Characteristics (Ta = 25°C)

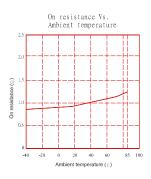
Item		Symbol	MIN.	TYP.	MAX.	Units	Conditions	
	LED Forward Voltage	VF		1.32	1.5	V	I⊧=10mA	
	Operation LED Current	Fon		1.50	5.0	mA		
Input	Recovery LED Current	Foff		0.35	0.5	mA		
	Recovery LED Voltage	V <sub>Foff</sub>	0.7			V		
							I⊧=5mA,I∟=100mA,	
Output	On-Resistance	Ron		0.80	2.00	Ω	Time to flow is within 1 sec.	
	Off-State Leakage	Leak	0.01	0.02	0.10	uA	   V∟=Rating	
	Current		0.01	0.02	0.10		T T T T T T T T T T T T T T T T T T T	
	Output Capacitance	Cout		87		pF	V∟=0, f=1MHz	
Transmis	Turn-On Time	Ton		0.35	0.8	ms	I⊧=5mA, I∟=100mA,	
sion	Turn-Off Time	Toff		0.03	0.2	ms		
Coupled	I/O Isolation Resistance	R <sub>I/O</sub>	10 <sup>10</sup>			Ω	DC500V	
Coupled	I/O Capacitance	Ci/o		0.8	1.5	pF	f=1MHz	

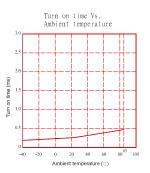
Please obey the following conditions to ensure proper device operation and resetting. Input LED current (Recommended value): IF ≥7mA and ≤30mA

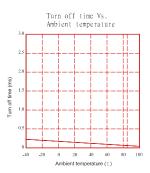


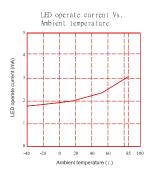
# **Engineering Data**

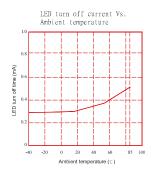


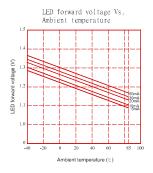


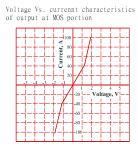


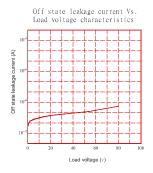


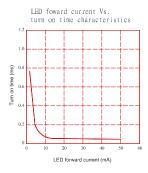


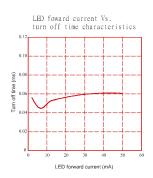




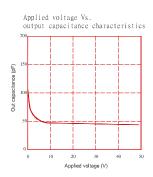








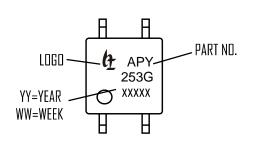
Page 3

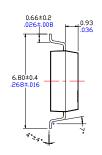




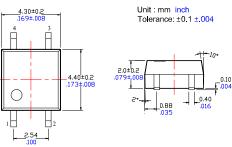
# **Dimensions and Package**

# Marking





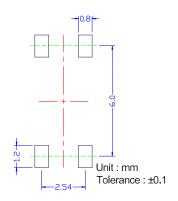




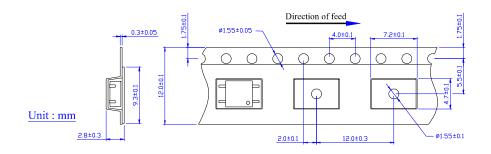
Lable



Recommended mounting pad (Top view)

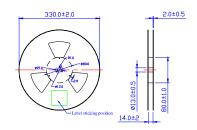


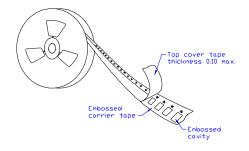
### Tape dimensions



**■ 6.** &

### Dimensions of tape reel

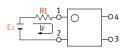


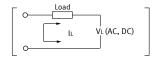




# **Using Methods**

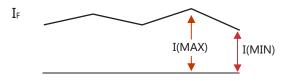
Examples of resistance value to control LED forward current (IF=5mA)





E1	R1 (Approx)
3.3V	300 Ω
5.0V	600 Ω
12V	1.9KΩ
24V	4.1K Ω

LED forward current must be more than 5mA , at I(MIN) ,and less than 30mA , at I(MAX).



### **Recommended Operating Conditions**

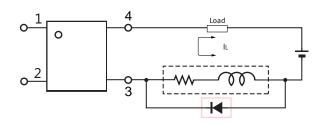
Please obey the following conditions to ensure proper device operation and resetting. Input LED current (Recommended value):

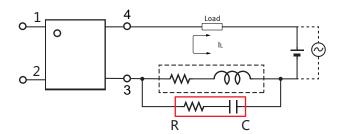
Characteristic	Symbol	Min	Тур.	Max	Unit
Forward current	lF	5.0	7.0	30	mA

### **Protection Circuit**

Clamp diode is connected in parallel with the load. Absorb capacity with external diode.

CR Snubber is connected in parallel with the load. Absorb capacity with buffer capacity.





When adding diodes, buffer circuits (C-R), and other protections, they need to be installed near the MOS RELAY to be effective. Adding protection elements may result in a slow reset time, so adjust them according to the actual situation before use.

Note: When developing designs using this product, perform the expected performance of the equipment under the operating conditions recommended by the guidelines in this document. Continuous use under heavy loads (including, but not limited to, the application of high temperatures/current/voltage and significant changes in temperature, etc.) may result in deterioration of the reliability of this product.



### **RESTRICTIONS ON PRODUCT USE**

APSEMI Co. and its subsidiaries and affiliates (collectively "APSEMI") reserve the right to make changes to all information contained in this document relating to hardware, software, and systems (collectively "Products").

No information in this document may be reproduced without the prior written permission of APSEMI. Even with APSEMI's written permission, this document may only be reproduced if it is guaranteed to be unaltered or missing.

APSEMI assumes no responsibility for unintended uses of the product:

Unintended uses include, but are not limited to, equipment used in nuclear facilities, equipment used in the aerospace industry, medical equipment, automobiles, trains, ships, and other transportation equipment, traffic signaling equipment, equipment used for the control of combustion or explosions, safety devices, elevators and escalators, equipment used in electrical power-related applications, and equipment used in financial-related applications.

APSEMI assumes no responsibility for the product if you use it for any purpose other than the specific purpose described in this document.

- The information contained herein is provided only as a guide for the use of the product.
  APSEMI assumes no responsibility for infringement of third party patents or any other intellectual property rights that may result from the use of the product. This document does not grant any license, express or implied, estoppel or otherwise, to any intellectual property.
- GaAs (Gallium Arsenide) is used in products and is harmful to humans. Inadvertent ingestion or absorption of GaAs can harm the human body, so handle the product with care and do not break, cut, crush, grind, chemically dissolve, or otherwise expose GaAs in the product.
- •Please be aware of environmental issues and use products in compliance with all applicable laws and regulations governing the inclusion or use of controlled substances, including but not limited to the EU RoHS Directive. APSEMI assumes no responsibility for damages or losses resulting from non-compliance with applicable laws and regulations.